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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	CANbus, FlexIO, I ² C, LINbus, SPI, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	89
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 24x12b SAR; D/A1x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/fs32k146hnt0vllt

- Communications interfaces
 - Up to three Low Power Universal Asynchronous Receiver/Transmitter (LPUART/LIN) modules with DMA support and low power availability
 - Up to three Low Power Serial Peripheral Interface (LPSPI) modules with DMA support and low power availability
 - Up to two Low Power Inter-Integrated Circuit (LPI2C) modules with DMA support and low power availability
 - Up to three FlexCAN modules (with optional CAN-FD support)
 - FlexIO module for emulation of communication protocols and peripherals (UART, I2C, SPI, I2S, LIN, PWM, etc).
 - Up to one 10/100Mbps Ethernet with IEEE1588 support and two Synchronous Audio Interface (SAI) modules.
- Safety and Security
 - Cryptographic Services Engine (CSEc) implements a comprehensive set of cryptographic functions as described in the SHE (Secure Hardware Extension) Functional Specification. Note: CSEc (Security) or EEPROM writes/erase will trigger error flags in HSRUN mode (112 MHz) because this use case is not allowed to execute simultaneously. The device will need to switch to RUN mode (80 MHz) to execute CSEc (Security) or EEPROM writes/erase.
 - 128-bit Unique Identification (ID) number
 - Error-Correcting Code (ECC) on flash and SRAM memories
 - System Memory Protection Unit (System MPU)
 - Cyclic Redundancy Check (CRC) module
 - Internal watchdog (WDOG)
 - External Watchdog monitor (EWM) module
- Timing and control
 - Up to eight independent 16-bit FlexTimers (FTM) modules, offering up to 64 standard channels (IC/OC/PWM)
 - One 16-bit Low Power Timer (LPTMR) with flexible wake up control
 - Two Programmable Delay Blocks (PDB) with flexible trigger system
 - One 32-bit Low Power Interrupt Timer (LPIT) with 4 channels
 - 32-bit Real Time Counter (RTC)
- Package
 - 32-pin QFN, 48-pin LQFP, 64-pin LQFP, 100-pin LQFP, 100-pin MAPBGA, 144-pin LQFP, 176-pin LQFP package options
- 16 channel DMA with up to 63 request sources using DMAMUX

Description Input Multiplexing sheet(s) attached with Reference Manual.

	Parameter	S32K11x		S32K14x			
		K116	K118	K142	K144	K146	K148
System	Core	Arm® Cortex™-M0+		Arm® Cortex™-M4F			
	Frequency	48 MHz		80 MHz (RUN mode) or 112 MHz (HSRUN mode) ¹			
	IEEE-754 FPU	○		●			
	Cryptographic Services Engine (CSEc) ¹	●		●			
	CRC module	1x		1x			
	ISO 26262	capable up to ASIL-B		capable up to ASIL-B			
	Peripheral speed	up to 48 MHz		up to 112 MHz (HSRUN)			
	Crossbar	●		●			
	DMA	●		●			
	External Watchdog Monitor (EWM)	○		●			
	Memory Protection Unit (MPU)	●		●			
	FIRC CMU	●		○			
	Watchdog	1x		1x			
	Low power modes	●		●			
	HSRUN mode ¹	○		●			
	Number of I/Os	up to 43	up to 58	up to 89	up to 128	up to 156	
	Single supply voltage	2.7 - 5.5 V		2.7 - 5.5 V			
	Ambient Operation Temperature (T _A)	-40°C to +105°C / +125°C		-40°C to +105°C / +125°C			
Memory	Flash	128 KB	256 KB	256 KB	512 KB	1 MB	2 MB ²
	Error Correcting Code (ECC)	●		●			
	System RAM (including FlexRAM and MTB)	17 KB	25 KB	32 KB	64 KB	128 KB	256 KB
	FlexRAM (also available as system RAM)	2 KB		4 KB			
	Cache	○		4 KB			
	EEPROM emulated by FlexRAM ¹	2 KB (up to 32 KB D-Flash)		4 KB (up to 64 KB D-Flash)			See footnote 3
	External memory interface	○		○			QuadSPI incl. HyperBus™
Timer	Low Power Interrupt Timer (LPIT)	1x		1x			
	FlexTimer (16-bit counter) 8 channels	2x (16)		4x (32)		6x (48)	8x (64)
	Low Power Timer (LPTMR)	1x		1x			
	Real Time Counter (RTC)	1x		1x			
	Programmable Delay Block (PDB)	1x		2x			
Analog	Trigger mux (TRGMUX)	1x (43)	1x (45)	1x (64)		1x (73)	1x (81)
	12-bit SAR ADC (1 Msps each)	1x (13)	1x (16)	2x (16)		2x (24)	2x (32)
	Comparator with 8-bit DAC	1x		1x			
Communication	10/100 Mbps IEEE-1588 Ethernet MAC	○		○			1x
	Serial Audio Interface (AC97, TDM, I2S)	○		○			2x
	Low Power UART/LIN (LPUART) (Supports LIN protocol versions 1.3, 2.0, 2.1, 2.2A, and SAE J2602)	2x		2x	3x		
	Low Power SPI (LPSPPI)	1x	2x	2x	3x		
	Low Power I2C (LPI2C)	1x		1x			2x
	FlexCAN (CAN-FD ISO/CD 11898-1)	1x (1x with FD)		2x (1x with FD)	3x (1x with FD)	3x (2x with FD)	3x (3x with FD)
	FlexIO (8 pins configurable as UART, SPI, I2C, I2S)	1x		1x			
IDEs	Debug & trace	SWD, MTB (1 KB), JTAG ⁴		SWD, JTAG (ITM, SWV, SWO)			SWD, JTAG (ITM, SWV, SWO), ETM
	Ecosystem (IDE, compiler, debugger)	NXP S32 Design Studio (GCC) + SDK, IAR, GHS, Arm®, Lauterbach, iSystems		NXP S32 Design Studio (GCC) + SDK, IAR, GHS, Arm®, Lauterbach, iSystems			
Other	Packages ⁵	32-pin QFN 48-pin LQFP	48-pin LQFP 64-pin LQFP	64-pin LQFP 100-pin LQFP	64-pin LQFP 100-pin LQFP 100-pin MAPBGA	64-pin LQFP 100-pin MAPBGA 100-pin LQFP 144-pin LQFP	100-pin MAPBGA 144-pin LQFP 176-pin LQFP

LEGEND:

○ Not implemented

● Available on the device

1 No write or erase access to Flash module, including Security (CSEc) and EEPROM commands, are allowed when device is running at HSRUN mode (112MHz) or VLPR mode.

2 Available when EEPROM, CSEc and Data Flash are not used. Else only up to 1,984 KB is available for Program Flash.

3 4 KB (up to 512 KB D-Flash as a part of 2 MB Flash). Up to 64 KB of flash is used as EEPROM backup and the remaining 448 KB of the last 512 KB block can be used as Data flash or Program flash. See chapter FTFC for details.

4 Only for Boundary Scan Register

5 See Dimensions section for package drawings

Figure 3. S32K1xx product series comparison

3 Ordering information

3.1 Selecting orderable part number

Not all part number combinations are available. See the attachment *S32K1xx_Orderable_Part_Number_List.xlsx* attached with the Datasheet for a list of standard orderable part numbers.

Table 5. V_{DD} supply LVR, LVD and POR operating requirements (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V_{LVW}	Falling low-voltage warning threshold	4.19	4.305	4.5	V	
V_{LVW_HYST}	LVW hysteresis	—	75	—	mV	1
V_{BG}	Bandgap voltage reference	0.97	1.00	1.03	V	

1. Rising threshold is the sum of falling threshold and hysteresis voltage.

4.6 Power mode transition operating behaviors

All specifications in the following table assume this clock configuration:

- RUN Mode:
 - Clock source: FIRC
 - SYS_CLK/CORE_CLK = 48 MHz
 - BUS_CLK = 48 MHz
 - FLASH_CLK = 24 MHz
- HSRUN Mode:
 - Clock source: SPL
 - SYS_CLK/CORE_CLK = 112 MHz
 - BUS_CLK = 56 MHz
 - FLASH_CLK = 28 MHz
- VLPR Mode:
 - Clock source: SIRC
 - SYS_CLK/CORE_CLK = 4 MHz
 - BUS_CLK = 4 MHz
 - FLASH_CLK = 1 MHz
- STOP1/STOP2 Mode:
 - Clock source: FIRC
 - SYS_CLK/CORE_CLK = 48 MHz
 - BUS_CLK = 48 MHz
 - FLASH_CLK = 24 MHz
- VLPS Mode: All clock sources disabled ¹

Table 6. Power mode transition operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit
t_{POR}	After a POR event, amount of time from the point V_{DD} reaches 2.7 V to execution of the first instruction across the operating temperature range of the chip.	—	325	—	μs

Table continues on the next page...

1.

- For S32K11x – FIRC/SOSC
- For S32K14x – FIRC/SOSC/SPLL

The following table shows the power consumption targets for S32K148 in various mode of operations measure at 3.3 V.

Table 9. Power consumption at 3.3 V

Chip/Device	Ambient Temperature (°C)		RUN@80 MHz (mA)		HSRUN@112 MHz (mA) ¹	
			Peripherals enabled + QSPI	Peripherals enabled + ENET + SAI	Peripherals enabled + QSPI	Peripherals enabled + ENET + SAI
S32K148	25	Typ	67.3	79.1	89.8	105.5
	85	Typ	67.4	79.2	95.6	105.9
		Max	82.5	88.2	109.7	117.4
	105	Typ	68.0	79.8	96.6	106.7
		Max	80.3	89.1	109.0	119.0
	125	Max	83.5	94.7	NA	

1. HSRUN mode must not be used at 125°C. Max ambient temperature for HSRUN mode is 105°C.

4.8 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V _{HBM}	Electrostatic discharge voltage, human body model	– 4000	4000	V	1
V _{CDM}	Electrostatic discharge voltage, charged-device model				2
	All pins except the corner pins	– 500	500	V	
	Corner pins only	– 750	750	V	
I _{LAT}	Latch-up current at ambient temperature of 125 °C	– 100	100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

4.9 EMC radiated emissions operating behaviors

EMC measurements to IC-level IEC standards are available from NXP on request.

I/O parameters

- Several I/O have both high drive and normal drive capability selected by the associated Portx_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details see IO Signal Description Input Multiplexing sheet(s) attached with the *Reference Manual*.
- When using ENET and SAI on S32K148, the overall device limits associated with high drive pin configurations must be respected i.e. On 144-pin LQFP the general purpose pins: PTA10, PTD0, and PTE4 must be set to low drive.
- Measured at input $V = V_{SS}$
- Measured at input $V = V_{DD}$

5.4 DC electrical specifications at 5.0 V Range

Table 12. DC electrical specifications at 5.0 V Range

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
V_{DD}	I/O Supply Voltage	4	—	5.5	V	
V_{ih}	Input Buffer High Voltage	$0.65 \times V_{DD}$	—	$V_{DD} + 0.3$	V	1
V_{il}	Input Buffer Low Voltage	$V_{SS} - 0.3$	—	$0.35 \times V_{DD}$	V	2
V_{hys}	Input Buffer Hysteresis	$0.06 \times V_{DD}$	—	—	V	
I_{ohGPIO} $I_{ohGPIO-HD_DSE_0}$	I/O current source capability measured when pad $V_{oh} = (V_{DD} - 0.8 \text{ V})$	5	—	—	mA	
I_{olGPIO} $I_{olGPIO-HD_DSE_0}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	5	—	—	mA	
$I_{ohGPIO-HD_DSE_1}$	I/O current source capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	20	—	—	mA	3
$I_{olGPIO-HD_DSE_1}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	20	—	—	mA	3
$I_{ohGPIO-FAST_DSE_0}$	I/O current sink capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	14.0	—	—	mA	4
$I_{olGPIO-FAST_DSE_0}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	14.5	—	—	mA	4
$I_{ohGPIO-FAST_DSE_1}$	I/O current sink capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	21	—	—	mA	4
$I_{olGPIO-FAST_DSE_1}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	20.5	—	—	mA	4
IOHT	Output high current total for all ports	—	—	100	mA	
IIN	Input leakage current (per pin) for full temperature range at $V_{DD} = 5.5 \text{ V}$					5
	All pins other than high drive port pins		0.005	0.5	μA	
	High drive port pins		0.010	0.5	μA	
R_{PU}	Internal pullup resistors	20		50	$k\Omega$	6
R_{PD}	Internal pulldown resistors	20		50	$k\Omega$	7

- For reset pads, same V_{ih} levels are applicable
- For reset pads, same V_{il} levels are applicable
- The strong pad I/O pin is capable of switching a 50 pF load up to 40 MHz.
- For reference only. Run simulations with the IBIS model and custom board for accurate results.

Table 24. Flash command timing specifications for S32K11x (continued)

Symbol	Description ¹		S32K116		S32K118		Unit		Notes
			Typ	Max	Typ	Max			
t _{ersscr}	Erase Flash Sector execution time	—	12	130	12	130	ms		2
t _{pgmsec1k}	Program Section execution time (1 KB flash)	—	5	—	5	—	ms		
t _{rd1all}	Read 1s All Block execution time	—	—	1.7	—	2.8	ms		
t _{rdonce}	Read Once execution time	—	—	30	—	30	μs		
t _{pgmonce}	Program Once execution time	—	90	—	90	—	μs		
t _{ersall}	Erase All Blocks execution time	—	150	1500	230	2500	ms		2
t _{vfykey}	Verify Backdoor Access Key execution time	—	—	35	—	35	μs		
t _{ersallu}	Erase All Blocks Unsecure execution time	—	150	1500	230	2500	ms		2
t _{pgmpart}	Program Partition for EEPROM execution time	32 KB EEPROM backup	71	—	71	—	ms		3
		64 KB EEPROM backup	—	—	—	—			
t _{setram}	Set FlexRAM Function execution time	Control Code 0xFF	0.08	—	0.08	—	ms		3
		32 KB EEPROM backup	0.8	1.2	0.8	1.2			
		48 KB EEPROM backup	—	—	—	—			
		64 KB EEPROM backup	—	—	—	—			
t _{eevr8b}	Byte write to FlexRAM execution time	32 KB EEPROM backup	385	1700	385	1700	μs		3-4
		48 KB EEPROM backup	—	—	—	—			
		64 KB EEPROM backup	—	—	—	—			
t _{eevr16b}	16-bit write to FlexRAM execution time	32 KB EEPROM backup	385	1700	385	1700	μs		3-4
		48 KB EEPROM backup	—	—	—	—			
		64 KB EEPROM backup	—	—	—	—			
t _{eevr32bers}	32-bit write to erased FlexRAM location execution time	—	360	2000	360	2000	μs		

Table continues on the next page...

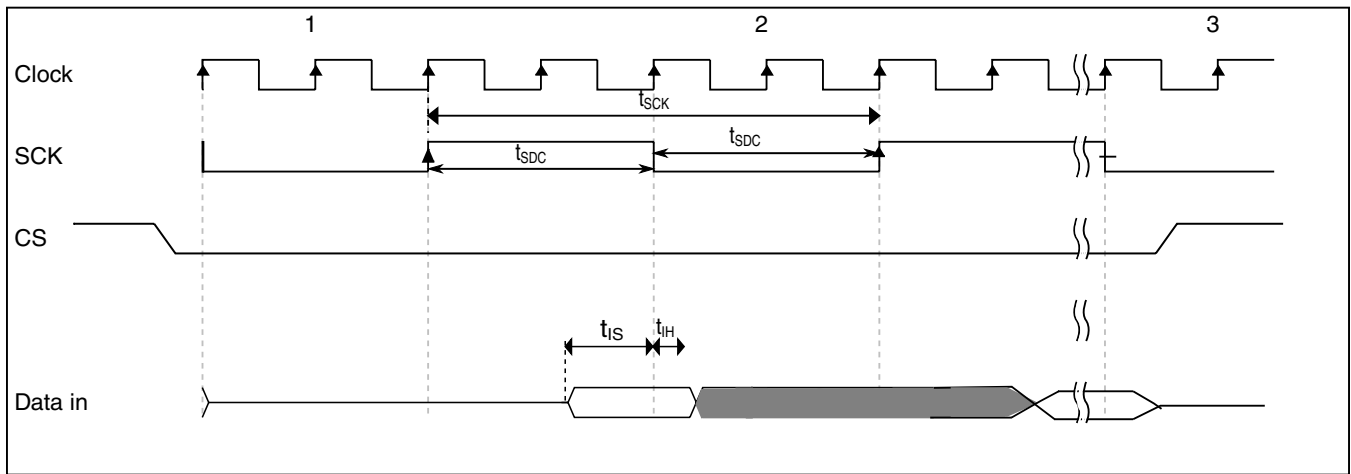


Figure 9. QuadSPI input timing (SDR mode) diagram

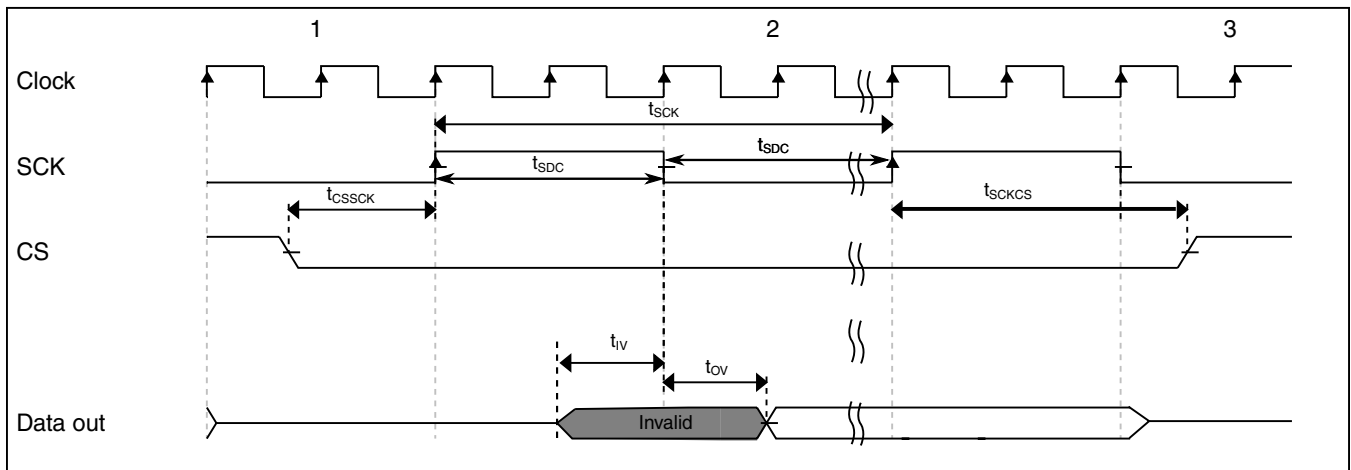
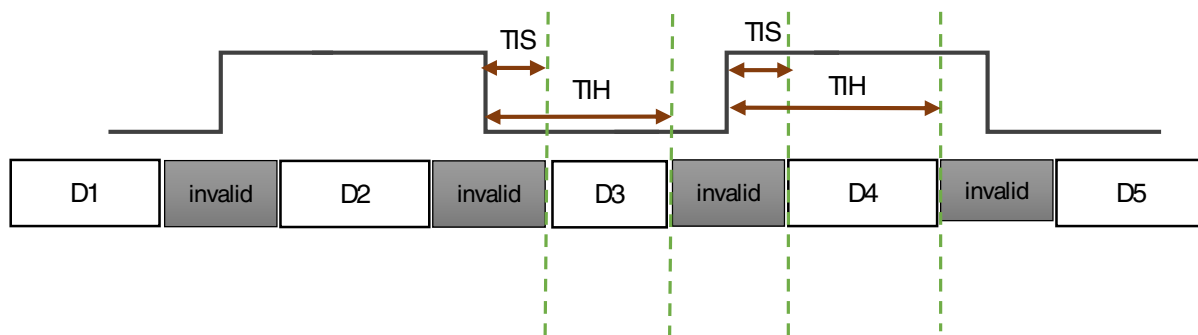


Figure 10. QuadSPI output timing (SDR mode) diagram



TIS – Setup Time

TIH – Hold Time

Figure 11. QuadSPI input timing (HyperRAM mode) diagram

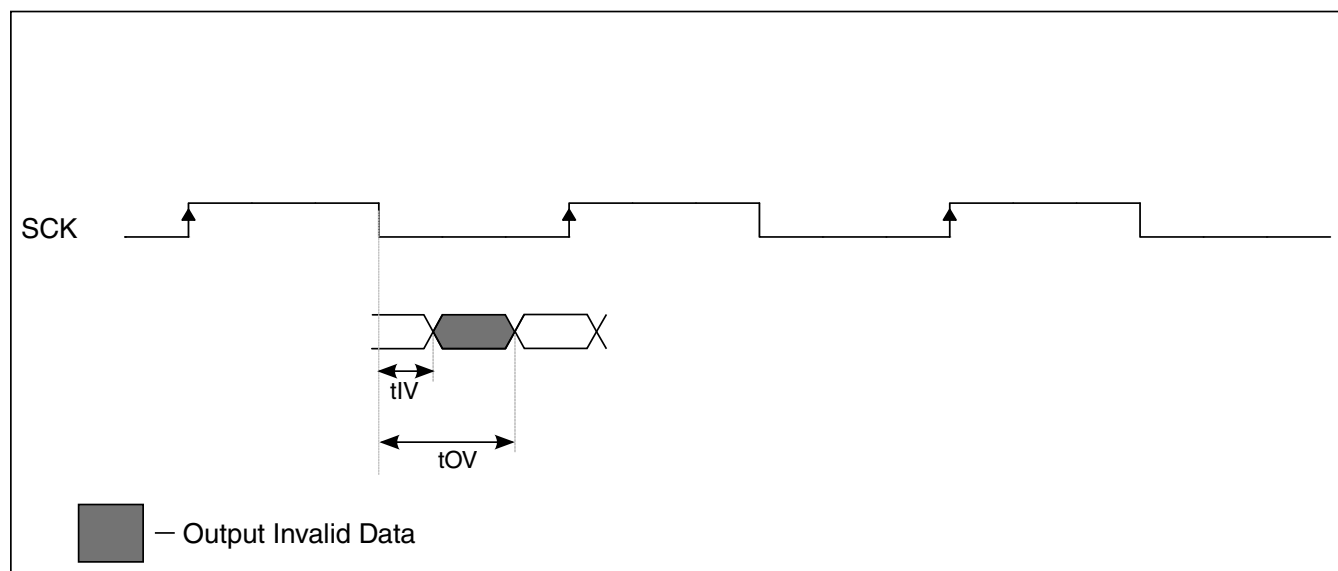


Figure 12. QuadSPI output timing (HyperRAM mode) diagram

6.4 Analog modules

6.4.1 ADC electrical specifications

6.4.1.1 12-bit ADC operating conditions

Table 27. 12-bit ADC operating conditions

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
V_{REFH}	ADC reference voltage high		See Voltage and current operating requirements for values	V_{DDA}	See Voltage and current operating requirements for values	V	2
V_{REFL}	ADC reference voltage low		See Voltage and current operating requirements for values	0	See Voltage and current operating requirements for values	mV	2
V_{ADIN}	Input voltage		V_{REFL}	—	V_{REFH}	V	
R_S	Source impedandance	$f_{ADCK} < 4 \text{ MHz}$	—	—	5	k Ω	
R_{SW1}	Channel Selection Switch Impedance		—	0.75	1.2	k Ω	
R_{AD}	Sampling Switch Impedance		—	2	5	k Ω	
C_{P1}	Pin Capacitance		—	10	—	pF	
C_{P2}	Analog Bus Capacitance		—	—	4	pF	
C_S	Sampling capacitance		—	4	5	pF	

Table continues on the next page...

6.4.2 CMP with 8-bit DAC electrical specifications

Table 31. Comparator with 8-bit DAC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
I _{DDHS}	Supply current, High-speed mode ¹				μA
	-40 - 125 °C	—	230	300	
I _{DDL}	Supply current, Low-speed mode ¹				μA
	-40 - 105 °C	—	6	11	
	-40 - 125 °C		6	13	
V _{AIN}	Analog input voltage	0	0 - V _{DDA}	V _{DDA}	V
V _{AIO}	Analog input offset voltage, High-speed mode				mV
	-40 - 125 °C	-25	±1	25	
V _{AIO}	Analog input offset voltage, Low-speed mode				mV
	-40 - 125 °C	-40	±4	40	
t _{DHSB}	Propagation delay, High-speed mode ²				ns
	-40 - 105 °C	—	35	200	
	-40 - 125 °C		35	300	
t _{DL}	Propagation delay, Low-speed mode ²				μs
	-40 - 105 °C	—	0.5	2	
	-40 - 125 °C	—	0.5	3	
t _{DH}	Propagation delay, High-speed mode ³				ns
	-40 - 105 °C	—	70	400	
	-40 - 125 °C	—	70	500	
t _{DL}	Propagation delay, Low-speed mode ³				μs
	-40 - 105 °C	—	1	5	
	-40 - 125 °C	—	1	5	
t _{IDH}	Initialization delay, High-speed mode ⁴				μs
	-40 - 125 °C	—	1.5	3	
t _{IDL}	Initialization delay, Low-speed mode ⁴				μs
	-40 - 125 °C	—	10	30	
V _{HYST0}	Analog comparator hysteresis, Hyst0				mV
	-40 - 125 °C	—	0	—	
V _{HYST1}	Analog comparator hysteresis, Hyst1, High-speed mode				mV
	-40 - 125 °C	—	19	66	
	Analog comparator hysteresis, Hyst1, Low-speed mode				
	-40 - 125 °C	—	15	40	
V _{HYST2}	Analog comparator hysteresis, Hyst2, High-speed mode				mV
	-40 - 125 °C	—	34	133	

Table continues on the next page...

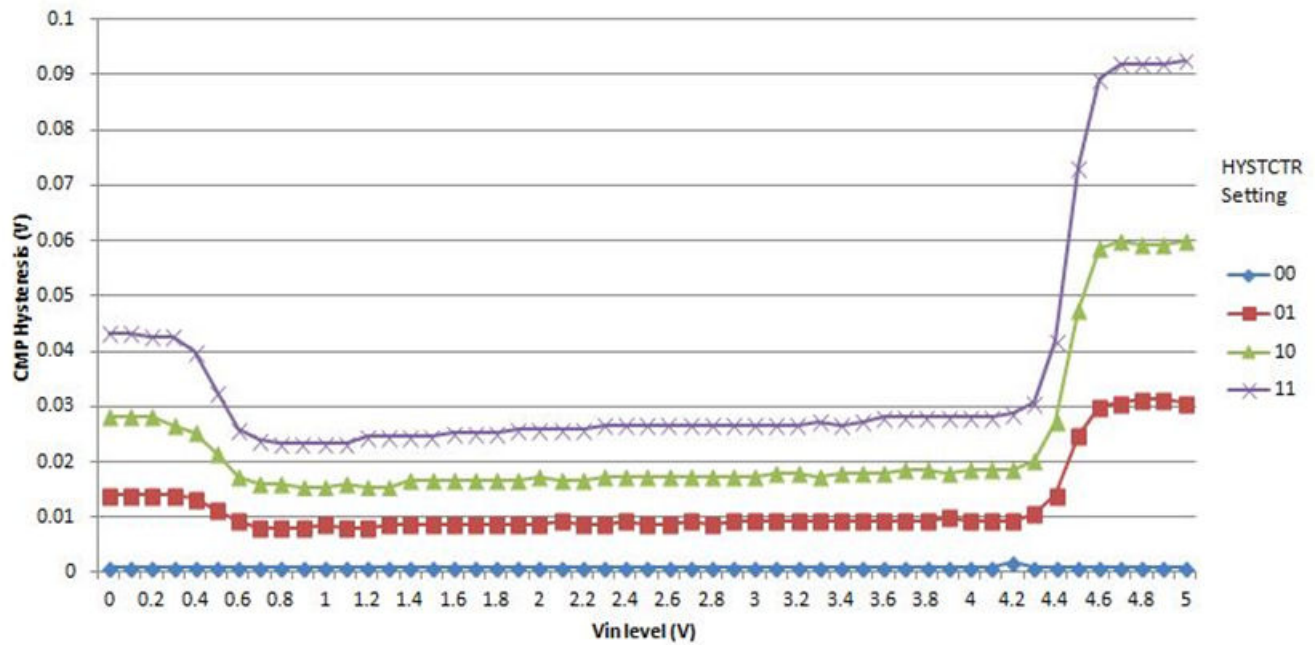


Figure 16. Typical hysteresis vs. Vin level (VDDA = 5 V, PMODE = 0)

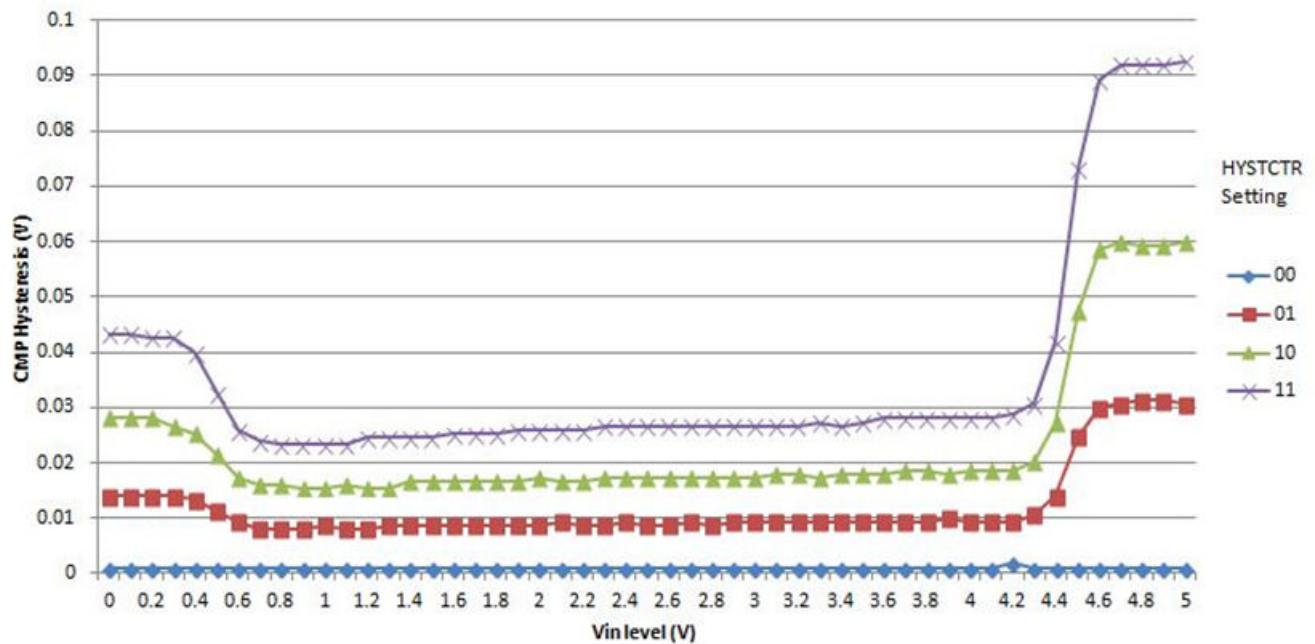


Figure 17. Typical hysteresis vs. Vin level (VDDA = 5 V, PMODE = 1)

6.5.4 FlexCAN electrical specifications

For supported baud rate, see section 'Protocol timing' of the *Reference Manual*.

6.5.5 SAI electrical specifications

The following table describes the SAI electrical characteristics.

- Measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN), the interface should be OFF.

Table 33. Master mode timing specifications

Symbol	Description	Min.	Max.	Unit
—	Operating voltage	2.97	3.6	V
S1	SAI_MCLK cycle time	40	—	ns
S2	SAI_MCLK pulse width high/low	45%	55%	MCLK period
S3	SAI_BCLK cycle time	80	—	ns
S4	SAI_BCLK pulse width high/low	45%	55%	BCLK period
S5	SAI_RXD input setup before SAI_BCLK	28	—	ns
S6	SAI_RXD input hold after SAI_BCLK	0	—	ns
S7	SAI_BCLK to SAI_TXD output valid	—	8	ns
S8	SAI_BCLK to SAI_TXD output invalid	-2	—	ns
S9	SAI_FS input setup before SAI_BCLK	28	—	ns
S10	SAI_FS input hold after SAI_BCLK	0	—	ns
S11	SAI_BCLK to SAI_FS output valid	—	8	ns
S12	SAI_BCLK to SAI_FS output invalid	-2	—	ns

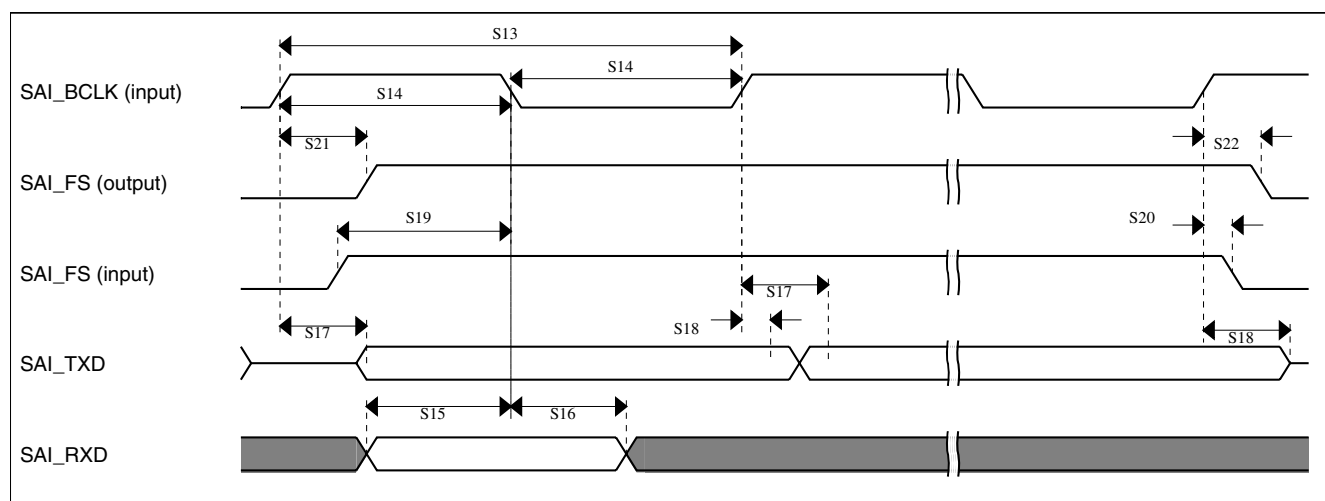


Figure 23. SAI Timing — Slave modes

6.5.6 Ethernet AC specifications

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

The following table describes the MII electrical characteristics.

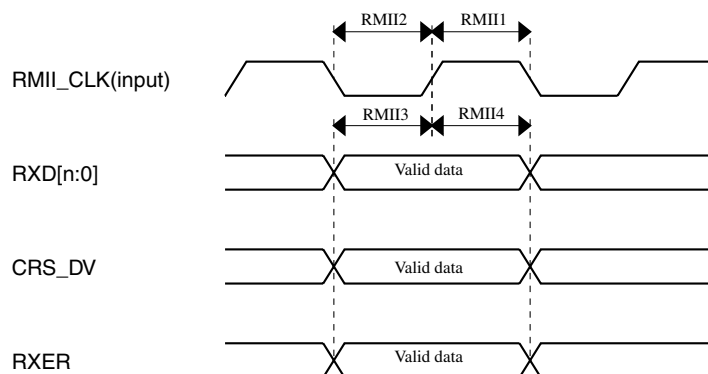
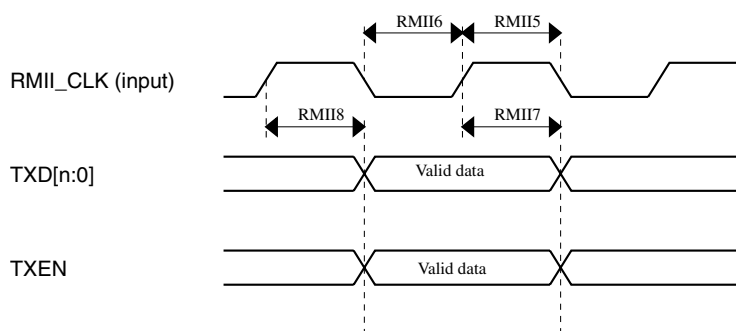
- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN), the interface should be OFF.

Table 35. MII signal switching specifications

Symbol	Description	Min.	Max.	Unit
—	RXCLK frequency	—	25	MHz
MII1	RXCLK pulse width high	35%	65%	RXCLK period
MII2	RXCLK pulse width low	35%	65%	RXCLK period
MII3	RXD[3:0], RXDV, RXER to RXCLK setup	5	—	ns
MII4	RXCLK to RXD[3:0], RXDV, RXER hold	5	—	ns
—	TXCLK frequency	—	25	MHz
MII5	TXCLK pulse width high	35%	65%	TXCLK period
MII6	TXCLK pulse width low	35%	65%	TXCLK period
MII7	TXCLK to TXD[3:0], TXEN, TXER invalid	2	—	ns
MII8	TXCLK to TXD[3:0], TXEN, TXER valid	—	25	ns

**Table 36. RMI signal switching specifications
(continued)**

Symbol	Description	Min.	Max.	Unit
RMII7	RMII_CLK to TXD[1:0], TXEN invalid	2	—	ns
RMII8	RMII_CLK to TXD[1:0], TXEN valid	—	15	ns

**Figure 26. RMI receive diagram****Figure 27. RMI transmit diagram**

The following table describes the MDIO electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN), the interface should be OFF.
- MDIO pin must have external Pull-up.

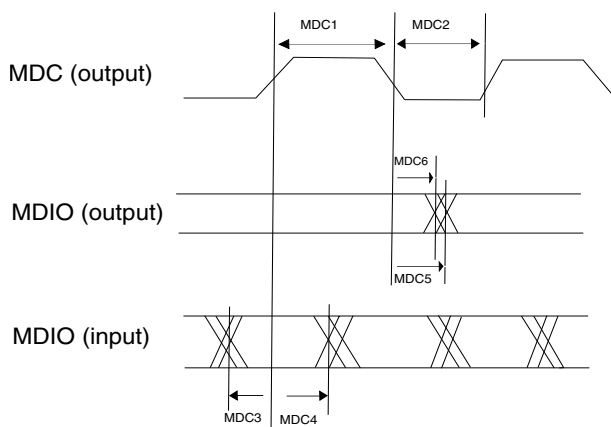
Table 37. MDIO timing specifications

Symbol	Description	Min.	Max.	Unit
—	MDC Clock Frequency	—	2.5	MHz

Table continues on the next page...

Table 37. MDIO timing specifications (continued)

Symbol	Description	Min.	Max.	Unit
MDC1	MDC pulse width high	40%	60%	MDC period
MDC2	MDC pulse width low	40%	60%	MDC period
MDC3	MDIO (input) to MDC rising edge setup	25	—	ns
MDC4	MDIO (input) to MDC rising edge hold	0	—	ns
MDC5	MDC falling edge to MDIO output valid (maximum propagation delay)	—	25	ns
MDC6	MDC falling edge to MDIO output invalid (minimum propagation delay)	-10	—	ns

**Figure 28. MII/RMII serial management channel timing diagram**

6.5.7 Clockout frequency

Maximum supported clock out frequency for this device is 20 MHz

6.6 Debug modules

6.6.1 SWD electrical specifications

Table 38. SWD electrical specifications

Symbol	Description	Run Mode				HSRUN Mode				VLPR Mode				Unit
		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
S1	SWD_CLK frequency of operation	-	25	-	25	-	25	-	25	-	10	-	10	MHz
S2	SWD_CLK cycle period	1/S1	-	1/S1	-	1/S1	-	1/S1	-	1/S1	-	1/S1	-	ns
S3	SWD_CLK clock pulse width	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	ns
S4	SWD_CLK rise and fall times	-	1	-	1	-	1	-	1	-	1	-	1	ns
S9	SWD_DIO input data setup time to SWD_CLK rise	4	-	4	-	4	-	4	-	16	-	16	-	ns
S10	SWD_DIO input data hold time after SWD_CLK rise	3	-	3	-	3	-	3	-	10	-	10	-	ns
S11	SWD_CLK high to SWD_DIO data valid	-	28	-	38	-	28	-	38	-	70	-	77	ns
S12	SWD_CLK high to SWD_DIO high-Z	-	28	-	38	-	28	-	38	-	70	-	77	ns
S13	SWD_CLK high to SWD_DIO data invalid	0	-	0	-	0	-	0	-	0	-	0	-	ns

Table 41. Thermal characteristics for 32-pin QFN and 48/64/100/144/176-pin LQFP package (continued)

Rating	Conditions	Symbol	Package	Values						Unit
				S32K116	S32K118	S32K142	S32K144	S32K146	S32K148	
Thermal resistance, Junction to Ambient (@ 200 ft/min) ^{1, 3}	Four layer board (2s2p)	R _{θJMA}	144	NA	NA	NA	NA	37	31	
			176	NA	NA	NA	NA	NA	30	
			32	26	NA	NA	NA	NA	NA	
			48	48	41	NA	NA	NA	NA	
			64	NA	37	36	36	35	NA	
			100	NA	NA	34	34	33	NA	
			144	NA	NA	NA	NA	36	30	
			176	NA	NA	NA	NA	NA	29	
Thermal resistance, Junction to Board ⁴	—	R _{θJB}	32	11	NA	NA	NA	NA	NA	
			48	33	24	NA	NA	NA	NA	
			64	NA	26	25	25	23	NA	
			100	NA	NA	25	25	24	NA	
			144	NA	NA	NA	NA	30	24	
			176	NA	NA	NA	NA	NA	24	
Thermal resistance, Junction to Case ⁵	—	R _{θJC}	32	NA	NA	NA	NA	NA	NA	
			48	23	19	NA	NA	NA	NA	
			64	NA	14	13	12	11	NA	
			100	NA	NA	13	12	11	NA	
			144	NA	NA	NA	NA	12	9	
			176	NA	NA	NA	NA	NA	9	
Thermal resistance, Junction to Case (Bottom) ⁶	—	R _{θJCBottom}	32	1	NA					
			48	NA						
			64							
			100							
			144							
			176							

Table continues on the next page...

Table 43. Revision History (continued)

Rev. No.	Date	Substantial Changes
		- Updated values for V_{REFH} and V_{REFL} to add reference to the section "voltage and current operating requirements" for Min and Max values - Updated footnote to Typ. - Removed footnote from RAS Analog source resistance - Updated figure: ADC input impedance equivalency diagram - In table: 12-bit ADC characteristics (2.7 V to 3 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) - Removed rows for V_{TEMP_S} and V_{TEMP25} - Updated footnote to Typ. - In table: 12-bit ADC characteristics (3 V to 5.5 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) - Removed rows for V_{TEMP_S} and V_{TEMP25} - Removed number for TUE - Updated footnote to Typ. - In table: Comparator with 8-bit DAC electrical specifications - Updated Typ. of I_{DDL5} Supply current, Low-speed mode - Updated Typ. of t_{DLSB} Propagation delay, Low-speed mode - Updated Typ. of t_{DHSS} Propagation delay, High-speed mode - Updated t_{DLSS} Propagation delay - Added row for t_{DDAC} Initialization and switching settling time - Updated footnote - Updated section LPSPi electrical specifications - Added section: SAI electrical specifications - Updated section: Ethernet AC specifications - Added section: Clockout frequency - Added section: Trace electrical specifications - Updated table: Table 41 : Updated numbers for S32K142 and S32K148 - Updated table: Table 42 : Updated numbers for S32K148 - Updated Document number for 32-pin QFN in topic Obtaining package dimensions
3	14 March 2017	- In Table 2 - Updated min. value of V_{DD_OFF} - Added parameter I_{INJSUM_AF} - Updated Power mode transition operating behaviors - Updated Power consumption - Updated footnote to T_{SPLL_LOCK} in SPLL electrical specifications - In 12-bit ADC electrical characteristics - Updated table: 12-bit ADC characteristics (2.7 V to 3 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) - Added typ. value to I_{DDA_ADC}, TUE, DNL, and INL - Added min. value to SMPLTS - Removed footnote 'All the parameters in this table ... ' - Updated table: 12-bit ADC characteristics (3 V to 5.5 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) - Added typ. value to I_{DDA_ADC} - Removed footnote 'All the parameters in this table ... ' - In Flash timing specifications — commands updated Max. value of t_{Vfykey} to 33 μs
4	02 June 2017	- In section: Block diagram, added block diagram for S32K11x series. - Updated figure: S32K1xx product series comparison. - In section: Selecting orderable part number , added reference to attachment S32K_Part_Numbers.xlsx. - In section: Ordering information - Updated figure: Ordering information. - In Table 1,

Table continues on the next page...

Table 43. Revision History

Rev. No.	Date	Substantial Changes
		- Added footnote 'For S32K11x – FIRC/SOSC/FIRC/LPO; For S32K14x – FIRC/SOSC/FIRC/LPO/SPLL' to 'VLPS Mode: All clock sources disabled' - Updated numbers for: - VLPR → VLPS - VLPS → VLPR 'RUN → Compute operation' - RUN → VLPS - RUN → VLPR - In Power consumption : - Updated specs for S32K142, S32K144, and S32K148 - Updated footnote 'Typical current numbers are indicative ...' - Updated footnote 'The S32K148 data ...' - Removed footnote 'Above S32K148 data is preliminary targets only' - Added new table 'Power consumption at 3.3 V' - In General AC specifications : - Updated max value and footnote of WFRST - Updated symbol for not filtered pulse to 'WNFRST', updated min value, removed max. value, and added footnote - Fixed naming conventions to align with DS in DC electrical specifications at 3.3 V Range and DC electrical specifications at 5.0 V Range - Updated specs for AC electrical specifications at 3.3 V range and AC electrical specifications at 5 V range - In Device clock specifications : - Updated f_{BUS} to 48 for 11x - Added footnote to f_{BUS} for 14x - In External System Oscillator frequency specifications : - Added specs for S32K11x - Updated 't_{dc_extal}' for S32K14x - Added footnote 'Frequencies below ...' to 'f_{ec_extal}' and 't_{dc_extal}' - Splitted Flash timing specifications — commands for S32K14x and S32K11x - Updated Flash timing specifications — commands for S32K14x - In Reliability specifications : - Added footnote 'Data retention period ...' for 'tnvmretp1k' and 'tnvmreteet' - Minor update in footnote for 'nnvmwree16' 'nnvmwree256' - In QuadSPI AC specifications : - Updated 'MCR[SCLKCFG[5]]' value to 0 - Updated 'Data Input Setup Time' HSRUN Internal DQS PAD Loopback value to 1.6 - Updated 'Data Input Setup Time' DDR External DQS min. value to 2 - Updated 'Data Input Hold Time' DDR External DQS min. value to 20 - Updated figure 'QuadSPI output timing (SDR mode) diagram' and 'QuadSPI input timing (HyperRAM mode) diagram' - In 12-bit ADC electrical characteristics : - Added note 'On reduced pin packages where ...' - Removed max. value of 'I_{DDA_ADC}' - Added note 'Due to triple ...' - In 12-bit ADC operating conditions, removed parameter 'ΔV_{DDA}' - In CMP with 8-bit DAC electrical specifications : - Updated Typ. and Max. values of 'I_{DDL5}' - Updated Typ. value of 't_{DHSB}' - Updated Typ. value of 'V_{HYST1}', 'V_{HYST2}', and 'V_{HYST3}' - In LPSPFI electrical specifications : - Updated 'f_{periph}' and 'f_{op}', and 't_{SPSCK}'

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